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## High-intensity highly charged ion beam production by superconducting ECR ion sources at IMP

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- Background and introduction
- High intensity HCI beam production by SECRAL and impact to HIRFL facility.
   3<sup>rd</sup> Gen. ECRIS
- Future development: IMP 45 GHz FECR.
   4<sup>th</sup> Gen. ECRIS
- Summary and conclusion

#### High power heavy ion accelerator requests intense HCI

Accelerator facility for rare isotope beam production requests high intensity primary ion beams, which actually very much depends on performance of the front-end ion source



#### MSU FRIB U<sup>33+</sup>+U<sup>34+</sup> 13 pµA/ CW







#### RIKEN RIBF U<sup>35+</sup> 500 eµA/ CW



SPIRAL2 Ar<sup>12+</sup> 1 emA/ CW

**CW**-intense highly charged ion(HCI) beams requested by RIB accelerator complex

## High power RIB accelerator requests intense HCI beams

#### **Pulsed**-intense highly charged ion (HCI) beams requested by RIB accelerator complex



GSI @FAIR U<sup>28+</sup> > 10emA pulsed

IMP HIAF U<sup>35+</sup> 50 pµA pulsed



Requirements of ion source for those high energy (GeV/u) high current heavy ion accelerators



 $E \sim Q^2$  for cyclotrons  $E \sim Q$  for linac

Higher power Simpler injection mode

# Developing intense highly charged ion source is both performance-effective and cost-effective.



#### 100 MeV/u SC heavy ion linac

	<sup>238</sup> U <sup>34+</sup>	<sup>238</sup> U <sup>46+</sup>	238U22+	
Injection E (MeV/u)	1.3	1.3	1.3	
Output E (MeV/u)	100	100	100	
Design I <sub>max</sub> (emA)	1.0	1.0	1.0	
SC cavity It is very much worthy of developing highly charged ion source				
SC cavities				
Solenoids	78	65	55	
CRM Reduced		11	16	
Total length (m)	288	225	197	
Budget reduced		>70 M\$ (MP not included)	>100 M\$ (MP not included)	

## Highly charged ECR ion source

#### HCI ion source: EBIS;LIS;ECRIS. Only ECRIS for HCI DC and pulsed beam

**ECRIS: Electron Resonance Cyclotron Ion Source** 



Higher Q and higher I  $\Longrightarrow$  Higher  $n_e \tau_i \Longrightarrow$  Higher  $\omega_{rf} \Longrightarrow$  Higher B That is why we need to build SC-ECRIS, and also good device to study ECRIS physics.



#### **Development of highly charged ECR ion source**

TRA

#### Past, present and future





## High intensity HCI sources: ECRIS

#### High performance superconducting ECRIS

		Parameters	Unit	State of the Art ECRISs
		ω <sub>rf</sub>	GHz	24~28
	SECRAL	P <sub>rf</sub>	kW	10.0
		<b>B</b> <sub>mirror</sub>	т	3.5~4.0/2.2~2.8
		B <sub>r</sub>	т	1.8~2.0
		Chamber ID	mm	Ø100~150
	SECRAL, SECRAL-II@IMP	<b>Mirror Length</b>	mm	400~500
VENUS@LBNL		HV	kV	30
	SCECRIS@RIKEN	<ul> <li>♦ V</li> <li>♦ ~</li> <li>♦ H</li> </ul>	ery hi ms p ligh b	gh charge state oulse to dc beam eam intensity





## High intensity HCI beam production by SECRAL and impact to HIRFL facility. 3<sup>rd</sup> Gen. ECRIS

- Future development: IMP 45 GHz FECR. 4<sup>th</sup> Gen. ECRIS
- Summary and conclusion

## **IMP existing heavy ion facility HIRFL**

IMP is the biggest nuclear physics research center in China for heavy ion basic-science and nuclear technology application





## Ion sources for SFC cyclotron





## **SECRAL ECR ion source**

Fully NbTi superconducting magnet ECR source

SECRAL was built in 2001-2005. Beam operation to HIRFL since 2007



#### **Conventional magnet structure of ECR ion source**



## Sextupole-in-Solenoid

C. Lyneis@presentation ICIS2009

SERSE/LNS, VENUS/LBNL, SuSi/MSU, SC-ECR/RIKEN,....

## **SECRAL** innovative magnet structure



## **SECRAL superconducting ECR ion source**



- SECRAL first beam:2005;
- Beam delivery for HIRFL accelerator since 2007
- 3000-4000 hours beam operation each year in the past 10 years.

## New microwave coupling system at SECRAL



- Ø32 mm TE<sub>01</sub> –traditional 28GHz
- Ø20 mm HE<sub>11</sub>
- Ø20 mmTE<sub>01</sub> shows the best results due to better coupling.
   Intensity increased by 20-50%









SECRAL beam current increasing with technologies

TRAF





#### **SECRAL II and Test Bench Layout**

#### SECRAL II was built for HIRFL linac new injector



**Record beam intensities produced by SECRAL and SECRAL II** 

**SECRAL I-II beam intensities and compared to LBNL VENUS** 



#### HCI beam production by 45 GHz ECR plasma at SECRAL II

#### World first beam test for HCI production with 45 GHz ECR plasma



#### 28+45+18 GHz three frequency heating



	VENUS	SECRAL	SECRAL-II
_	28+18 GHz	24+18 GHz	45+28+18 GHz
Ion	(eµA)	(eµA)	(еµА)
<sup>129</sup> Xe <sup>38+</sup>	26	22.6	53
Xe <sup>42+</sup>	6		17
Xe <sup>44+</sup>	2	1	3.9
Xe <sup>45+</sup>	0.88	0.1	1.3

H.W. Zhao, et.al. RSI, (2018)

**Intense beam stability from SECRAL** 



<sup>209</sup>Bi<sup>31+</sup> 329 eµA more than 2 hours stability test operation at 3.7 kW

## Intense beam stability from SECRAL II

SECRAL-II <sup>86</sup>Kr<sup>26+</sup> 120 euA





#### **SECRAL** beam emittance

Emittance vs. beam intensity









RF: 24 GHz, P<sub>rf</sub>= 1.0 kW, HV= 20 kV, Io= 4.8 emA, Bi<sup>31+</sup>= 115 eµA



RF: 24 GHz+18 GHz, P<sub>rf</sub>= 3.4 kW+ 0.3 kW, HV= 23 kV, Io= 10 emA, Bi<sup>31+</sup>= 330 eμA

#### T. Nakagawa talk at ECRIS2018



#### **SECRAL operation status at HIRFL**





Intense heavy ion beams

- Intense highly charged ion beams
- ~35,000 hours beam time up to June, 2018
- Demonstrate its reliability
- No any other 3<sup>rd</sup> generation SC ECRIS in the world has ever run such long-time beams





- SFC beam intensities for heavy ions such as Ni, Kr, Xe,Bi, U, increased by a factor 10
- SSC beam intensities for heavy ions such as Ni, Kr, Xe,Bi, increased by a factor >50
- CSR is able to run those heavy ion beams such as Ni. Xe Bi, U with SFC as an injector.

SECRAL impact to HIRFL performance of beam energy

TEAP







- High intensity HCI beam production by SECRAL and impact to HIRFL facility.
   3<sup>rd</sup> Gen. ECRIS
- Future development: IMP 45 GHz FECR. 4<sup>th</sup> Gen. ECRIS





## **IMP future heavy ion facility HIAF**

#### Bring-N: 0.8 GeV/A, 3×10<sup>10</sup>ppp

#### HIAF: 2018-2024 Budget: 1.5+1.1 B CNY, approved Site: Huizhou, Guangdong



Higher microwave frequency 40-60 GHz is the most straight forward path to achieve high beam intensity for HCI ECRIS.



**IMP ECR ion source development** 

## The world first 45 GHz ECRIS----FECR

TIMP

#### **FECR:** first Fourth generation ECR ion source





#### **FECR key parameters**

Microwave	45 GHz/20 kW	
Magnet conductor	Nb <sub>3</sub> Sn	
Axial fields ( T )	6.5/1.0/3.5	
Sextupole field (T)	3.8@r=75 mm	
Maximum field ( T )	11.8 T	
Maximum stress (MPa)	150	
Magnet bore ( mm )	>Ø160	
Stored energy (MJ)	1.6	
Extraction (kV)	50	
Typical beam	1.0 emA U <sup>35+</sup>	

#### Beams and intensities expected from FECR

$^{129}$ Xe <sup>30+</sup>	>1000 µA
<sup>129</sup> Xe <sup>45+</sup>	> 50 µA
<sup>209</sup> Bi <sup>31+</sup>	>1000 µA
<sup>209</sup> Bi <sup>55+</sup>	> 50 µA
<sup>238</sup> U <sup>35+</sup>	>1000 µA
<sup>238</sup> U <sup>41+</sup>	> 200 µA
238U56+	> 30 µA



#### **45 GHz FECR ion source**



## **FECR Nb<sub>3</sub>Sn magnet mechanical structure**



This Nb<sub>3</sub>Sn magnet is being built by a Chinese company without collaboration with ATAP/LBNL. DOE did not approve such collaboration.

#### Coil fabrication

- Nb<sub>3</sub>Sn single wire winding (sextupole coil)
- Curing with precise configuration
- Large number of current leads
- Insulation
- Integration and assembling
  - Precise fabrication and assembling
  - Tolerance control
- Quench protection
  - Quench detection and protection
- Dynamic heat load from 45 GHz ECR plasma
  - Heat load may > 2 W/kW



#### **Prototype of FECR Nb<sub>3</sub>Sn magnet**



Prototype magnet is being fabricated by a company in China

## Status of FECR Nb<sub>3</sub>Sn magnet prototype



**Prototyping Nb<sub>3</sub>Sn sextupole coil** 

800 A no quench



## **Summary and conclusion**

- Accelerator facility for rare isotope beam production requests high intensity primary ion beam which actually very much depends on performance of the front-end ion source.
- SC ECRIS with higher microwave frequency is the most straight forward path to achieve high beam intensity for HCI.
- SECRAL&SECRAL II, the world best performance highly charged ECR ion source,, have produced many record beam intensities, such as O<sup>6+</sup> 6.7 emA ; Ar<sup>11-14+</sup>,Kr<sup>18+</sup> Xe<sup>26+</sup> > 1 emA ; Xe<sup>42+</sup>. Bi<sup>50+</sup>, U<sup>50+</sup> > 10 eµA.
- SECRAL has delivered HCI beams for HIRFL accelerator for almost 10 years, which has demonstrated its good long-term reliability and stability, and has greatly enhanced HIRFL performance in terms of beam intensity and energy.
- SC ECRIS, such as SECRAL &SECRAL II, may provide some new research opportunities for rare isotope beam physics because of demonstrated such level of ion source performance.
- Future development of SC ECRIS is the 4<sup>th</sup> generation with microwave heating frequency 40-60 GHz. IMP is developing the world first 4<sup>th</sup> Gen. ECRIS—45 GHz FECR, which may get beam by July 2020.

# Thanks for your attention 谢谢!

**Option of FECR magnet Nb<sub>3</sub>Sn superconductor** 

## Wire $\sqrt{}$

#### **Pros:**

- No extra cabling process
- Lower power supply currents (<1000 A)</li>
- Simpler HTS current lead solution
- HV platform feasible
- Cost efficient

#### Cons:

- Sextupole coil winding more difficult ×
- Quench protection issues ×
  - ~1.6 MJ stored energy
  - Higher qench voltage
- Superconducting joints
- Higher failure risk ×



#### OST M-Grade Nb<sub>3</sub>Sn wire

## Cable

#### Pros:

- Successful examples of Accelerator magnets
- Good reliability
- Easier quench protection sys.

#### Cons:

- Not feasible for HV platform ×
  - 100~300 kV
  - 10 kA PSs on Platform
- Cryogenic solution×
- Higher cost
- Extra Cabling R&D

# (Becomosed)

**Rutherford Cable** 





#### **FECR optimized Magnetic Design**

#### **Coil and conductor operation parameters**

	Nominal engineering current density	Nominal wire current	Nominal peak field	Load factor
	J <sub>e</sub> (A/mm²)	I <sub>e</sub> (A)	В <sub>реак-п</sub> (Т)	(%)
Sext.	320	654	11.3	75.9
Inj.	365	692	11.8	78.2
Mid.	-200	380	5.0	36.5
Ext.	330	626	9.7	67.3

Assuming packing factor of 65% (sextupole) and 70% (solenoid) Wire: OST M-Grade Nb3Sn Ø1.43 mm with 0.13 mm S-glass included

Conductor performance, stability

